

Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Non-Repetitive Peak Reverse Voltage		V_{RM}	100	V
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V _{RRM} V _{RWM} V _R	75	٧
RMS Reverse Voltage		V _{R(RMS)}	53	V
Forward Continuous Current	(Note 6)	I _{FM}	300	mA
Average Rectified Output Current	(Note 6)	Ι _Ο	200	mA
Non-Repetitive Peak Forward Surge Current	@ t = 1.0μs @ t = 1.0s	I _{FSM}	2.0 1.0	A

Thermal Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6)	P_d	150	mW
Thermal Resistance Junction to Ambient Air	(Note 6)	$R_{ hetaJA}$	833	°C/W
Operating and Storage Temperature Range		T _j , T _{STG}	-65 to +150	℃

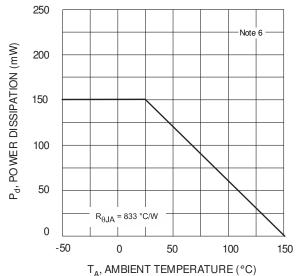
Electrical Characteristics (@ $T_A = +25$ °C, unless otherwise specified.)

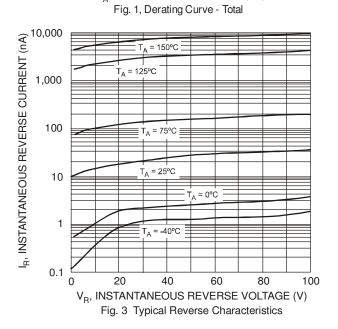
Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 7)	$V_{(BR)R}$	75	_	V	$I_R = 100 \mu A$
Forward Voltage	V _F	١	0.715 0.855 1.0 1.25	٧	I _F = 1.0mA I _F = 10mA I _F = 50mA I _F = 150mA
Leakage Current (Note 7)	I _R	l	1.0 50 30 25	μΑ μΑ Α nA	$V_{R} = 75V$ $V_{R} = 75V$, $T_{i} = +150$ °C $V_{R} = 25V$, $T_{j} = +150$ °C $V_{R} = 20V$
Total Capacitance	C _T		2.0	pF	$V_R = 0, f = 1.0MHz$
Reverse Recovery Time	t _{rr}		4.0	ns	$I_F = I_R = 10 \text{mA},$ $I_{rr} = 0.1 \times I_R, R_L = 100 \Omega$

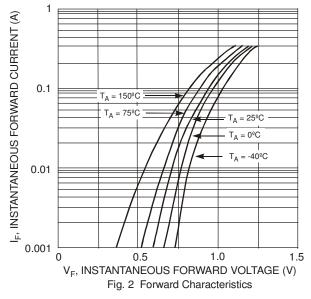
<sup>Notes:
6. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
7. Short duration pulse test used to minimize self-heating effect.</sup>











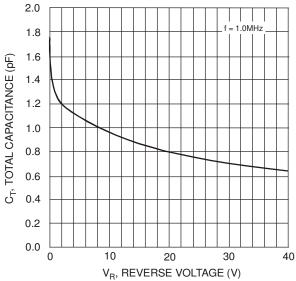
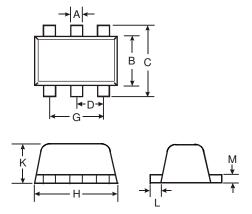


Fig. 4 Typical Capacitance vs. Reverse Voltage



Package Outline Dimensions

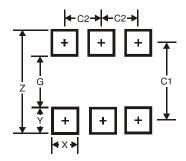
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT563				
Dim	Min	Max	Тур		
Α	0.15	0.30	0.20		
В	1.10	1.25	1.20		
С	1.55	1.70	1.60		
D	-	-	0.50		
G	0.90	1.10	1.00		
Н	1.50	1.70	1.60		
K	0.55	0.60	0.60		
L	0.10	0.30	0.20		
M	0.10	0.18	0.11		
All	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.2
G	1.2
Х	0.375
Υ	0.5
C1	1.7
C2	0.5



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